

Transient Voltage Suppressors for ESD Protection

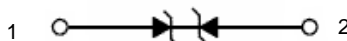
FEATURES:

- ▮ Low Leakage
- ▮ Response Time is Typically < 1 ns
- ▮ IEC61000-4-2 Level 4 ESD Protection
- ▮ These are Pb-Free Devices
- ▮ We declare that the material of product compliance with RoHS requirements and Halogen Free.

Circuit Diagram & Pin Configuration:



SOD-882



DEVICE MARKING AND ORDERING INFORMATION

Device	Marking	Shipping
TESDN241BD82	4C	10000/Tape&Reel

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
IEC 61000-4-2 (ESD) Air Contact Contact discharge		±30 ±30	kV kV
Total Power Dissipation on FR-5 Board (Note 1) @ T _A =25	PD	200	mW
Junction and Storage Temperature Range	T _J ,T _{STG}	-55 to 150	
Lead Solder Temperature – Maximum (10 Second Duration)	TL	260	

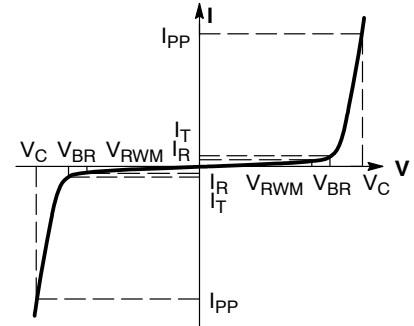
Stresses exceeding Maximum Ratings may damage the device. Maximum Rating are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. FR-5 = 1.0*0.75*0.62 in.

Electrical Parameter

($T_A = 25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter
I_{PP}	Maximum Reverse Peak Pulse Current
V_C	Clamping Voltage @ I_{PP}
V_{RWM}	Working Peak Reverse Voltage
I_R	Maximum Reverse Leakage Current @ V_{RWM}
V_{BR}	Breakdown Voltage @ I_T
I_T	Test Current
P_{pk}	Peak Power Dissipation
C	Capacitance @ $V_R = 0$ and $f = 1.0 \text{ MHz}$



Electrical Parameter ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Device	$V_{RWM} (V)$	$I_R (\mu A)$ @ V_{RWM}	$V_{BR} (V) *$ @ $I_T = 1 \text{ mA}$	$I_{PP} (A) **$	$V_C (V) **$ @ $I_{PP} = 1 A$	$V_C (V) **$ @ $I_{PP} = 5 A$	$P_{PK} (W) **$	$C (pF)$ $V_R=0V, f=1\text{MHz};$
	Max	Max	Min	Max	Max	Max	Max	Max
TESDN241BD82	24	0.1	26	5	29	35	175	30

* V_{BR} is measured with a pulse test current I_T at an ambient temperature of 25°C .

** Surge current waveform per Figure 1.

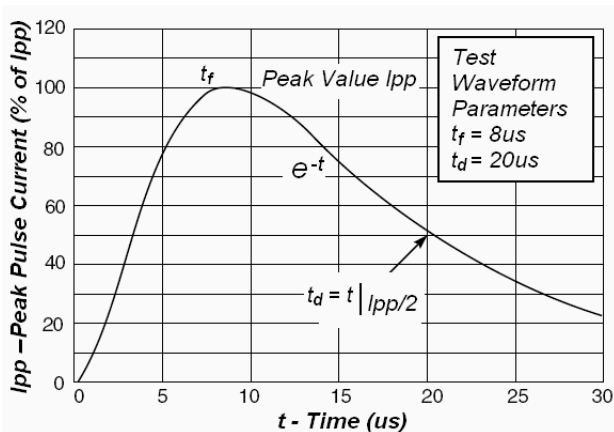


Fig 1. Pulse Waveform

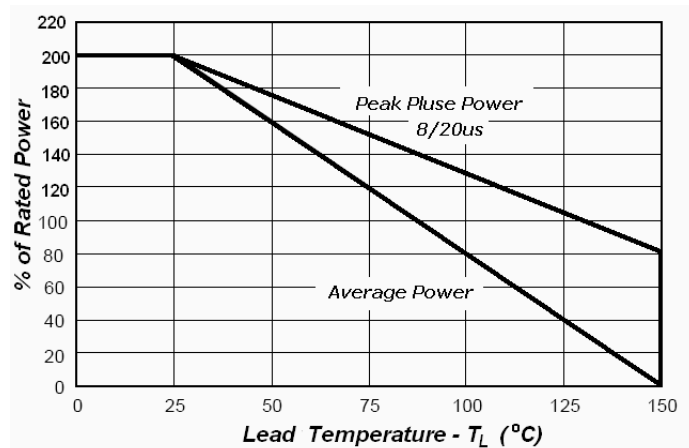
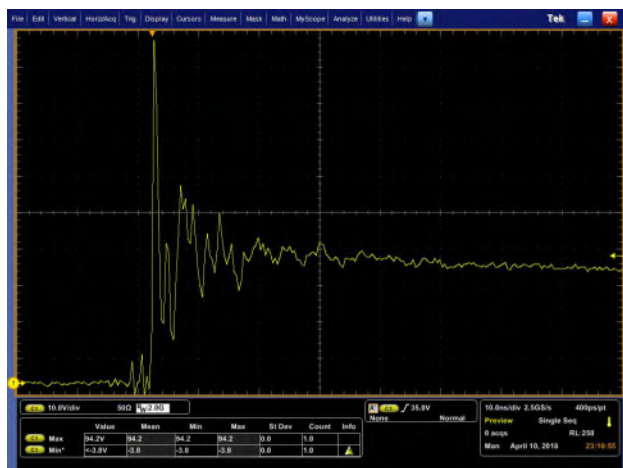
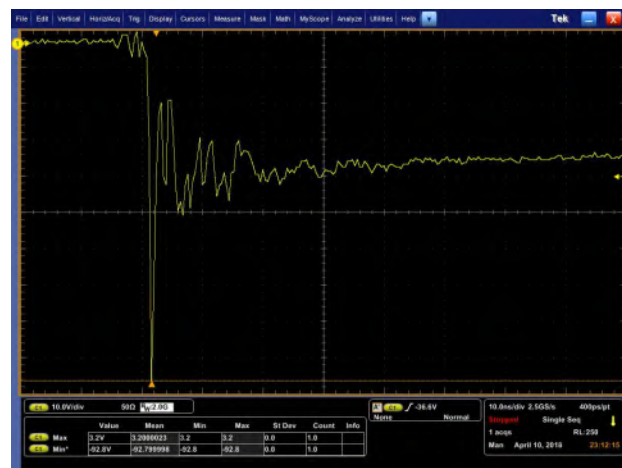


Fig2.Power Derating Curve



**Figure 3.ESD Elamping Voltage Screenshot
Positive 8 kV Econtact per IEE61000-4-2**



**Figure 4.ESD Elamping Voltage Screenshot
Negative 8 kV Econtact per IEE61000-4-2**

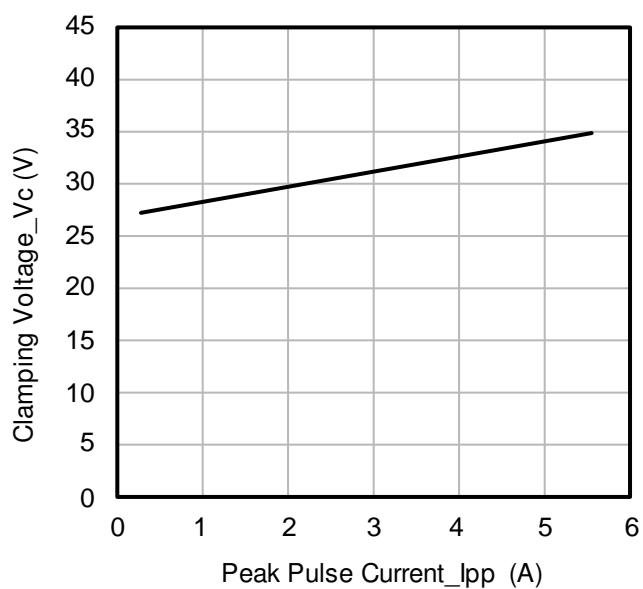
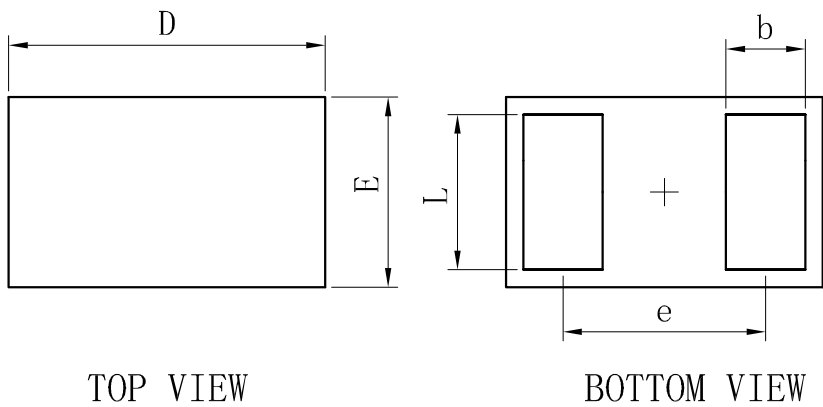
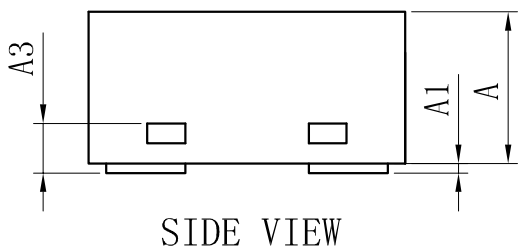


Fig 5 .Clamping Voltage vs. Peak Pulse Current

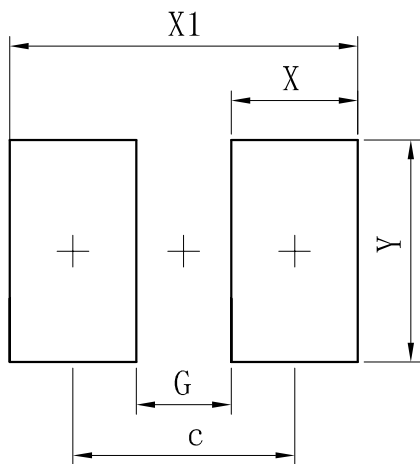
OUTLINE AND DIMENSIONS



SOD882			
Dim	Min	Typ	Max
D	0.95	1.00	1.05
E	0.55	0.60	0.65
e	–	0.64	–
L	0.44	0.49	0.54
b	0.20	0.25	0.30
A	0.43	0.48	0.53
A1	0	–	0.05
A3	0.127REF.		
All Dimensions in mm			



SOLDERING FOOTPRINT



Dimensions	(mm)
c	0.70
G	0.30
X	0.40
X1	1.10
Y	0.70

NOTICE

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The product listed herein is designed to be used with ordinary electronic equipment or devices, and not designed to be used with equipment or devices which require high level of reliability and the malfunction of which would directly endanger human life (such as medical instruments, transportation equipment, aerospace machinery, nuclear-reactor controllers, fuel controllers and other safety devices), Tinysemi elec Co., Ltd., or anyone on its behalf, assumes no responsibility or liability for any damages resulting from such improper use of sale.

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